

Agenda

## OSIRIS M12 Progress Meeting

Date: June 29th, 2016

Venue: ECSEL Building, Avenue de la toison d'or 56-60, B-1060 Bruxelles

Duration	Time	Topic	Organisation	Person
0:20	9:00	Coffee (hopefully)		
0:20	9:20	Introduction - Contractual status	III-V Lab	D. Mazerolle / S. Delage
0:10	9:40	WP1. SiC Growth - Introduction	LIU	Örjan Danielsson
0:15	9:50	WP1. SiC substrate	Norstel	Björn Magnusson
0:20	10:05	WP1. SiC epitaxy growth	LIU	Ole Kordina
0:30	10:25	WP1. <sup>28</sup> Si-isotope separation technique	Isosilicon	Bruno Ceccaroli
0:10	10:55	WP2. GaN Heterostructures - Introduction LIU	LIU	Örjan Danielsson
0:10	11:05	WP2. GaN Heterostructures LIU	LIU	Jr-Tai Chen
0:10	11:15	WP2. GaN Heterostructures III-Vlab	III-V Lab	Piero Gamarra
0:10	11:25	WP3. Active Devices - Introduction	UMS	Christophe Chang
0:15	11:35	WP3. HEMT devices	III-V Lab	Olivier Patard
0:15	11:50	WP3. Active Devices - SiC devices	Ascatron	Sergey Reshanov?
1:30	12:05	Lunch		
0:15	13:35	WP4. Device Assessment	III-V Lab	Christian Dua
0:15	13:50	WP4. Device Assessment - STUBA	STUBA	Jaroslav Kovac
0:15	14:05	WP4. Device Assessment - Intraspec Technologies	INTRASPEC	Guillaume Bascoul
0:15	14:20	WP4. Device Assessment - Ascatron	Ascatron	Sergey Reshanov?
0:15	14:35	WP4. Device Assessment - CIMAP	CIMAP	P. Ruterana
0:10	14:50	WP5. Exploitation and Dissemination	CIMAP	P. Ruterana
0:10	15:00	WP5. Stuba e-Learning	STUBA	Jaroslav Kovac Jr
0:30	15:10	Project Planning / Risk assessment - Mitigation plan	Örjan Danielsson	All
0:20	15:40	Final discussion - Action plan	Sylvain Delage	All
	16:00	End of Meeting		